

## OVERVIEW

The SM5022 series are crystal oscillator module ICs fabricated in NPC's Molybdenum-gate CMOS, that incorporate high-frequency, low current consumption oscillator and output buffer circuits. Feedback

resistors and high-frequency capacitors are built-in, eliminating the need for external components to make a stable fundamental-harmonic oscillator.

## FEATURES

- Up to 30MHz operation
- Fundamental oscillation
- Capacitors CG, CD built-in
- Inverter amplifier feedback resistor built-in
- TTL input level
- 4 mA ( $V_{DD} = 2.7\text{ V}$ ) drive capability
- 8 mA ( $V_{DD} = 4.5\text{ V}$ ) drive capability
- Output three-state function
- 2.7 to 5.5 V supply voltage (AxA series)
- 4.5 to 5.5 V supply voltage (BxA series)
- Oscillator frequency output ( $f_O$ ,  $f_O/2$ ,  $f_O/4$ ,  $f_O/8$  determined by internal connection)
- 6-pin SOT (SM5022xAH)
- Chip form (CF5022xA)

## SERIES CONFIGURATION

Version <sup>1</sup>	Supply voltage		Recommended operating frequency range (MHz)		Built-in capacitance (pF)		gm ratio	Rf (kΩ)	Output frequency	Output level	Standby output state
	Chip	SOT	3V	5V	C <sub>G</sub>	C <sub>D</sub>					
SM5022A1AH	2.7 to 5.5	2.7 to 5.5	4 to 24	4 to 30	8	10	1	600	f <sub>o</sub>	CMOS	High impedance
SM5022A2AH	2.7 to 5.5	2.7 to 5.5	4 to 24	4 to 30	-	-	1	600	f <sub>o</sub>	CMOS	High impedance
SM5022A3AH	2.7 to 5.5	2.7 to 5.5	4 to 30	4 to 30	8	10	1	600	f <sub>o</sub> /2	CMOS	High impedance
SM5022A4AH	2.7 to 5.5	2.7 to 5.5	4 to 30	4 to 30	-	-	1	600	f <sub>o</sub> /2	CMOS	High impedance
SM5022A5AH	2.7 to 5.5	2.7 to 5.5	4 to 30	4 to 30	8	10	1	600	f <sub>o</sub> /4	CMOS	High impedance
SM5022A7AH	2.7 to 5.5	2.7 to 5.5	4 to 30	4 to 30	8	10	1	600	f <sub>o</sub> /8	CMOS	High impedance
SM5022B1AH	4.5 to 5.5	4.5 to 5.5	×	4 to 30	8	10	1	600	f <sub>o</sub>	TTL	High impedance

1. Chip form devices have designation CF5022xA.

Note: Recommended operating frequency is not the guaranteed value but is measured using NPC's standard crystal.

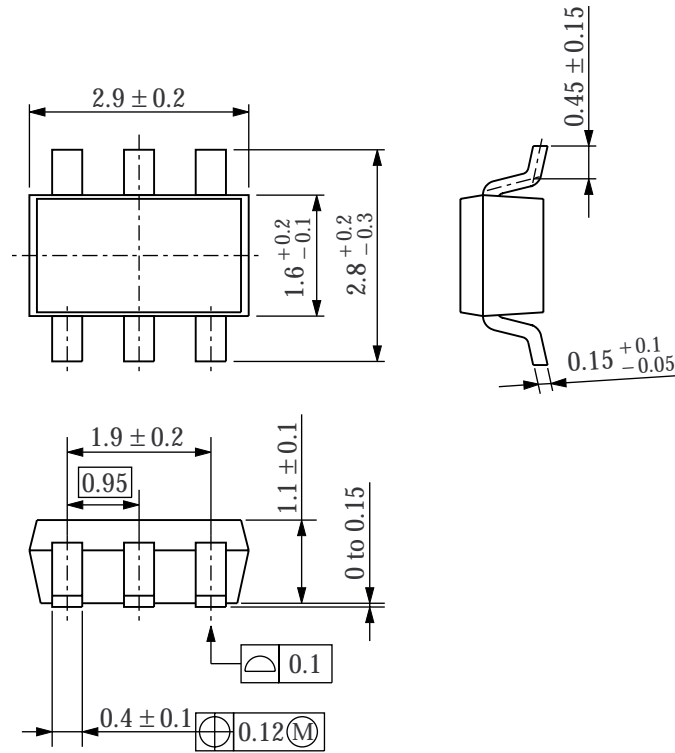
## ORDERING INFORMATION

Device	Package
SM5022xAH	6-pin SOT
CF5022xA-2	Chip form

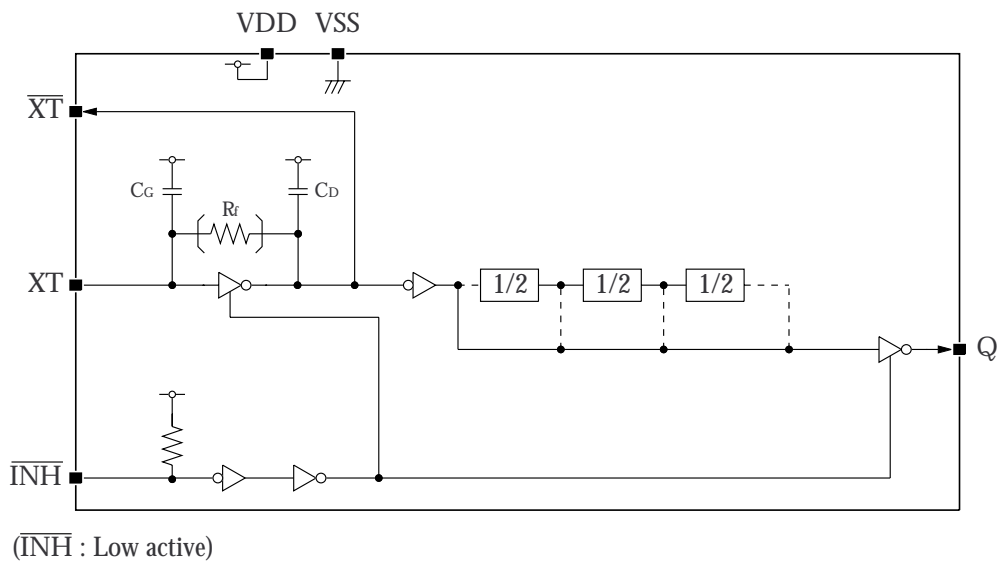
**PACKAGE DIMENSIONS**

(UNIT : mm)

- 6-pin SOT

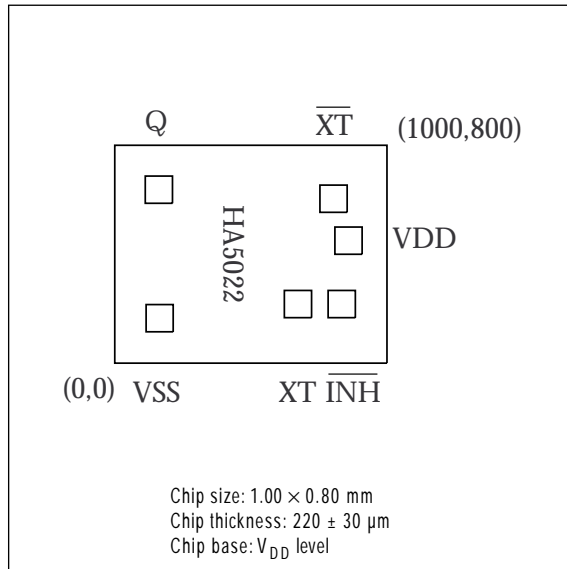


**BLOCK DIAGRAM**



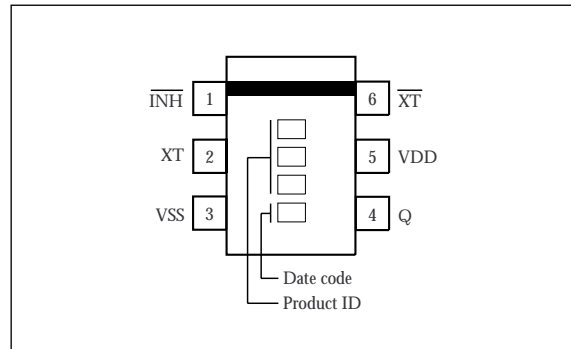
**PAD LAYOUT**

(Unit :  $\mu\text{m}$ )



**PINOUT**

(Top View)



Version	Product ID
SM5022A1AH	A00
SM5022A2AH	A01
SM5022A3AH	A02
SM5022A4AH	A03
SM5022A5AH	A04
SM5022A7AH	A05
SM5022B1AH	A06

**PIN DESCRIPTION and PAD DIMENSIONS**

Number	Name	I/O	Description	Pad dimensions [ $\mu\text{m}$ ]	
				X	Y
1	$\overline{\text{INH}}$	I	Output state control input. High impedance when LOW. Pull-up resistor built in	834	217
2	XT	I	Amplifier input. Crystal oscillator connection pins. Crystal oscillator connected between XT and $\overline{\text{XT}}$	637	217
3	VSS	-	Ground	165	165
4	Q	O	Output. Output frequency ( $f_0, f_0/2, f_0/4, f_0/8$ ) determined by internal connection	162	637
5	VDD	-	Supply voltage	859	450
6	$\overline{\text{XT}}$	O	Amplifier output. Crystal oscillator connection pins. Crystal oscillator connected between XT and $\overline{\text{XT}}$	804	604

## SPECIFICATIONS

### Absolute Maximum Ratings

$$V_{SS} = 0 \text{ V}$$

Parameter	Symbol	Condition	Rating	Unit
Supply voltage range	$V_{DD}$		-0.5 to 7.0	V
Input voltage range	$V_{IN}$		-0.5 to $V_{DD} + 0.5$	V
Output voltage range	$V_{OUT}$		-0.5 to $V_{DD} + 0.5$	V
Operating temperature range	$T_{opr}$		-40 to 85	°C
Storage temperature range	$T_{stg}$	Chip form	-65 to 150	°C
		6-pin SOT	-55 to 125	
Output current	$I_{OUT}$		13	mA
Power dissipation	$P_D$	6-pin SOT	250	mW

### Recommended Operating Conditions

#### 3 V operation: A×A series

$$V_{SS} = 0 \text{ V}, f \leq 30\text{MHz}, C_L \leq 15\text{pF}$$

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Supply voltage	$V_{DD}$		2.7	-	3.6	V
Input voltage	$V_{IN}$		$V_{SS}$	-	$V_{DD}$	V
Operating temperature	$T_{OPR}$		-20	-	80	°C

#### 5 V operation: A×A series/ B×A series

$$V_{SS} = 0 \text{ V}, f \leq 30\text{MHz}, C_L \leq 15\text{pF}$$

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Supply voltage	$V_{DD}$		4.5	-	5.5	V
Input voltage	$V_{IN}$		$V_{SS}$	-	$V_{DD}$	V
Operating temperature	$T_{OPR}$		-20	-	80	°C

## Electrical Characteristics

### 3 V operation: A×A series

$V_{DD} = 2.7$  to  $3.6$  V,  $V_{SS} = 0$  V,  $T_a = -20$  to  $80$  °C unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit	
			min	typ	max		
HIGH-level output voltage	$V_{OH}$	Q: Measurement cct 1, $V_{DD} = 2.7$ V, $I_{OH} = 4$ mA	2.1	2.4	–	V	
LOW-level output voltage	$V_{OL}$	Q: Measurement cct 2, $V_{DD} = 2.7$ V, $I_{OL} = 4$ mA	–	0.3	0.4	V	
Output leakage current	$I_Z$	Q: Measurement cct 2, $V_{DD} = 3.6$ V, $\overline{INH} = LOW$ , $V_{OH} = V_{DD}$	–	–	10	$\mu$ A	
		Q: Measurement cct 2, $V_{DD} = 3.6$ V, $\overline{INH} = LOW$ , $V_{OL} = V_{SS}$	–	–	10		
HIGH-level input voltage	$V_{IH}$	$\overline{INH}$	2.0	–	–	V	
LOW-level input voltage	$V_{IL}$	$\overline{INH}$	–	–	0.5	V	
Current consumption	$I_{DD}$	$\overline{INH} = open$ , Measurement cct 3, load cct 1, $C_L = 15$ pF, 30 MHz crystal oscillator	–	4	7	mA	
$\overline{INH}$ pull-up resistance	$R_{UP}$	Measurement cct 4	25	100	250	k $\Omega$	
Feedback resistance	$R_f$	Measurement cct 5	200	600	1000	k $\Omega$	
Built-in capacitance	$C_G$	Design value, determined by the internal wafer pattern	SM5022A1AH, CF5022A1A SM5022A3AH, CF5022A3A SM5022A5AH, CF5022A5A SM5022A7AH, CF5022A7A	7.44	8	8.56	pF
	$C_D$			9.3	10	10.7	pF

### 5 V operation: A×A series/ B×A series

$V_{DD} = 4.5$  to  $5.5$  V,  $V_{SS} = 0$  V,  $T_a = -20$  to  $80$  °C unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit	
			min	typ	max		
HIGH-level output voltage	$V_{OH}$	Q: Measurement cct 1, $V_{DD} = 4.5$ V, $I_{OH} = 8$ mA	3.9	4.2	–	V	
LOW-level output voltage	$V_{OL}$	Q: Measurement cct 2, $V_{DD} = 4.5$ V, $I_{OL} = 8$ mA	–	0.3	0.4	V	
Output leakage current	$I_Z$	Q: Measurement cct 2, $V_{DD} = 5.5$ V, $\overline{INH} = LOW$ , $V_{OH} = V_{DD}$	–	–	10	$\mu$ A	
		Q: Measurement cct 2, $V_{DD} = 5.5$ V, $\overline{INH} = LOW$ , $V_{OL} = V_{SS}$	–	–	10		
HIGH-level input voltage	$V_{IH}$	$\overline{INH}$	2.0	–	–	V	
LOW-level input voltage	$V_{IL}$	$\overline{INH}$	–	–	0.8	V	
Current consumption	$I_{DD}$	$\overline{INH} = open$ , Measurement cct 3, load cct 1, $C_L = 15$ pF, 30 MHz crystal oscillator	SM5022A×AH, CF5022A×A	–	7	12	mA
		$\overline{INH} = open$ , Measurement cct 3, load cct 2, $C_L = 15$ pF, 30 MHz crystal oscillator	SM5022B×AH, CF5022B×A	–	7	12	
$\overline{INH}$ pull-up resistance	$R_{UP}$	Measurement cct 4	25	100	250	k $\Omega$	
Feedback resistance	$R_f$	Measurement cct 5	200	600	1000	k $\Omega$	
Built-in capacitance	$C_G$	Design value, determined by the internal wafer pattern	SM5022A1AH, CF5022A1A SM5022A3AH, CF5022A3A SM5022A5AH, CF5022A5A SM5022A7AH, CF5022A7A SM5022B1AH, CF5022B1A	7.44	8	8.56	pF
	$C_D$			9.3	10	10.7	pF

## Switching Characteristics

### CMOS (AxA series)

#### 3 V operation

$V_{DD} = 2.7$  to  $3.6$  V,  $V_{SS} = 0$  V,  $T_a = -20$  to  $80$  °C unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit	
			min	typ	max		
Output rise time	$t_{r1}$	Measurement cct 6, load cct 1, $C_L = 15$ pF	0.2 $V_{DD}$ to 0.8 $V_{DD}$	–	5	10	ns
			0.1 $V_{DD}$ to 0.9 $V_{DD}$	–	10	20	
Output fall time	$t_{f1}$	Measurement cct 6, load cct 1, $C_L = 15$ pF	0.8 $V_{DD}$ to 0.2 $V_{DD}$	–	5	10	ns
			0.9 $V_{DD}$ to 0.1 $V_{DD}$	–	10	20	
Output duty cycle <sup>1</sup>	Duty	Measurement cct 6, load cct 1, $T_a = 25$ °C, $V_{DD} = 3$ V, $C_L = 15$ pF, $f = 30$ MHz	45	–	55	%	
Output disable delay time <sup>2</sup>	$t_{pLZ}$	Measurement cct 7, load cct 1, $T_a = 25$ °C, $V_{DD} = 3$ V, $C_L = 15$ pF	–	–	100	ns	
Output enable delay time <sup>2</sup>	$t_{pZL}$		–	–	100	ns	

1. Determined by the lot monitor.

2. Oscillator stop function is built-in. When  $\overline{INH}$  goes LOW, normal output stops. When  $\overline{INH}$  goes HIGH, normal output is not resumed until after the oscillator start-up time has elapsed.

#### 5 V operation

$V_{DD} = 4.5$  to  $5.5$  V,  $V_{SS} = 0$  V,  $T_a = -20$  to  $80$  °C unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Output rise time	$t_{r2}$	Measurement cct 6, load cct 1, 0.1 $V_{DD}$ to 0.9 $V_{DD}$ , $C_L = 15$ pF	–	3.5	7	ns
Output fall time	$t_{f2}$	Measurement cct 6, load cct 1, 0.9 $V_{DD}$ to 0.1 $V_{DD}$ , $C_L = 15$ pF	–	3.5	7	ns
Output duty cycle <sup>1</sup>	Duty	Measurement cct 6, load cct 1, $T_a = 25$ °C, $V_{DD} = 5$ V, $C_L = 15$ pF, $f = 30$ MHz	45	–	55	%
Output disable delay time <sup>2</sup>	$t_{pLZ}$	Measurement cct 7, load cct 1, $T_a = 25$ °C, $V_{DD} = 5$ V, $C_L = 15$ pF	–	–	100	ns
Output enable delay time <sup>2</sup>	$t_{pZL}$		–	–	100	ns

1. Determined by the lot monitor.

2. Oscillator stop function is built-in. When  $\overline{INH}$  goes LOW, normal output stops. When  $\overline{INH}$  goes HIGH, normal output is not resumed until after the oscillator start-up time has elapsed.

**TTL (B×A series)**

**5 V operation**

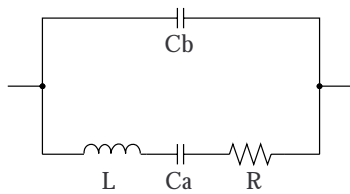
$V_{DD} = 4.5$  to  $5.5$  V,  $V_{SS} = 0$  V,  $T_a = -20$  to  $80$  °C unless otherwise noted.

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Output rise time	$t_{r3}$	Measurement cct 6, load cct 2, 0.4V to 2.4V, $C_L = 15$ pF	-	2.5	7	ns
Output fall time	$t_{f3}$	Measurement cct 6, load cct 2, 2.4V to 0.4V, $C_L = 15$ pF	-	2.5	7	ns
Output duty cycle <sup>1</sup>	Duty	Measurement cct 6, load cct 2, $T_a = 25$ °C, $V_{DD} = 5$ V, $C_L = 15$ pF, $f = 30$ MHz	45	-	55	%
Output disable delay time <sup>2</sup>	$t_{PLZ}$	Measurement cct 7, load cct 2, $T_a = 25$ °C, $V_{DD} = 5$ V, $C_L = 15$ pF	-	-	100	ns
Output enable delay time <sup>2</sup>	$t_{PZL}$		-	-	100	ns

1. Determined by the lot monitor.

2. Oscillator stop function is built-in. When  $\overline{INH}$  goes LOW, normal output stops. When  $\overline{INH}$  goes HIGH, normal output is not resumed until after the oscillator start-up time has elapsed.

**Current consumption and Output waveform with NPC's standard crystal**



f (MHz)	R (Ω)	L (mH)	Ca (fF)	Cb (pF)
30	17.2	4.36	6.46	2.26

**FUNCTIONAL DESCRIPTION**

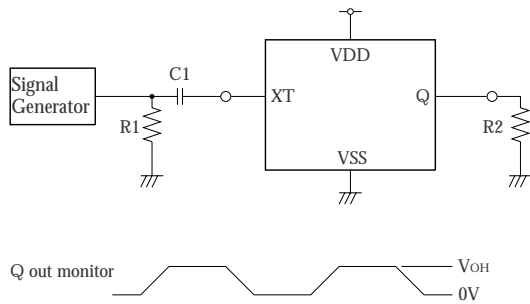
**Standby Function**

When  $\overline{INH}$  goes LOW, the oscillator output on Q goes high impedance.

$\overline{INH}$	Q	Oscillator
HIGH (or open)	Any $f_0$ , $f_0/2$ , $f_0/4$ , or $f_0/8$ output frequency	Normal operation
LOW	High impedance	Stopped

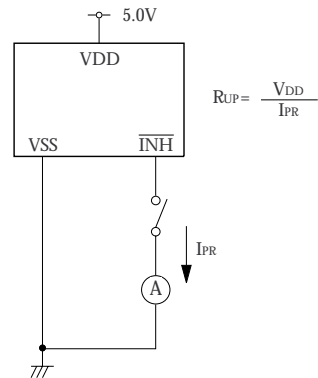
## MEASUREMENT CIRCUITS

### Measurement cct 1

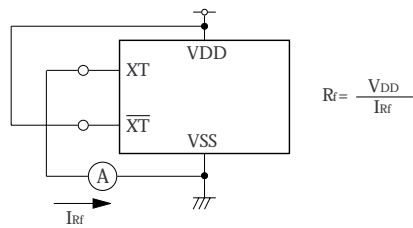


2.0V<sub>p-p</sub>, 10MHz sine wave input signal (3V operation)  
 3.5V<sub>p-p</sub>, 10MHz sine wave input signal (5V operation)  
 C1 : 0.001μF  
 R1 : 50Ω  
 R2 : 525Ω (3V operation)  
 490Ω (5V operation)

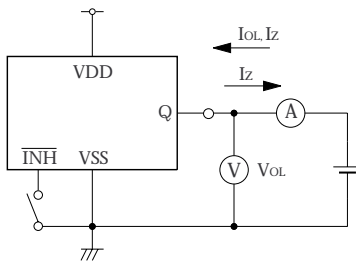
### Measurement cct 4



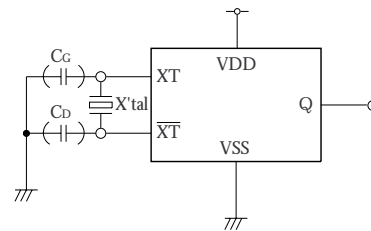
### Measurement cct 5



### Measurement cct 2

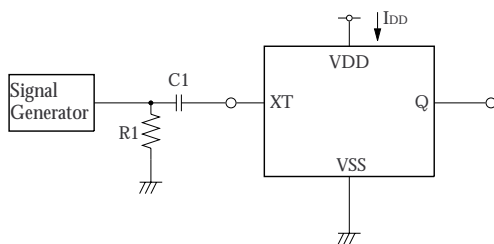


### Measurement cct 6



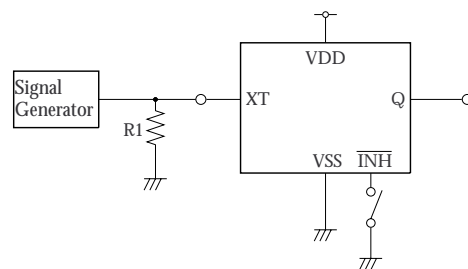
C<sub>G</sub>, C<sub>D</sub> : 10pF (5022A2, 5022A4)

### Measurement cct 3



2.0V<sub>p-p</sub>, 30MHz sine wave input signal (3V operation)  
 3.5V<sub>p-p</sub>, 30MHz sine wave input signal (5V operation)  
 C1 : 0.001μF  
 R1 : 50Ω

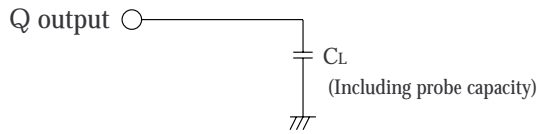
### Measurement cct 7



R1 : 50Ω

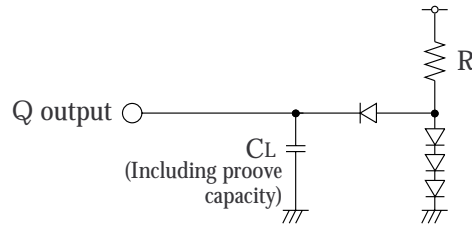


**Load cct 1**



$C_L = 15\text{pF}$

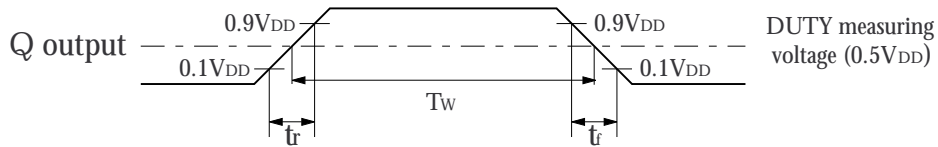
**Load cct 2**



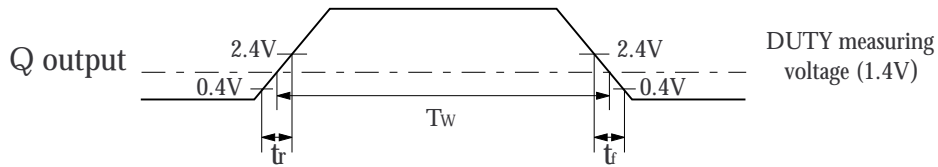
$C_L = 15\text{pF}$   
 $R = 800\Omega$

**Switching Time Measurement Waveform**

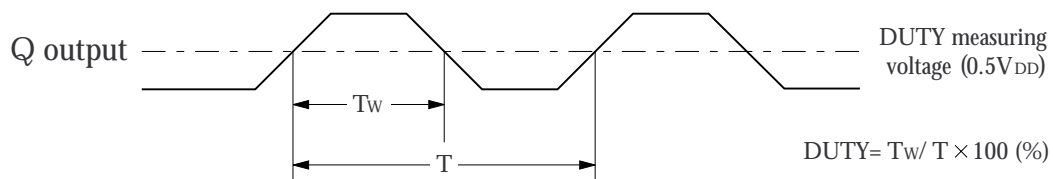
**Output duty level (CMOS)**



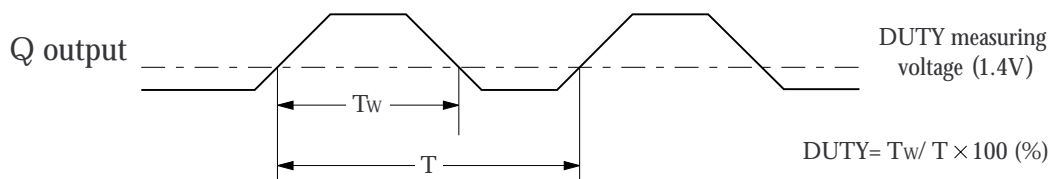
**Output duty level (TTL)**



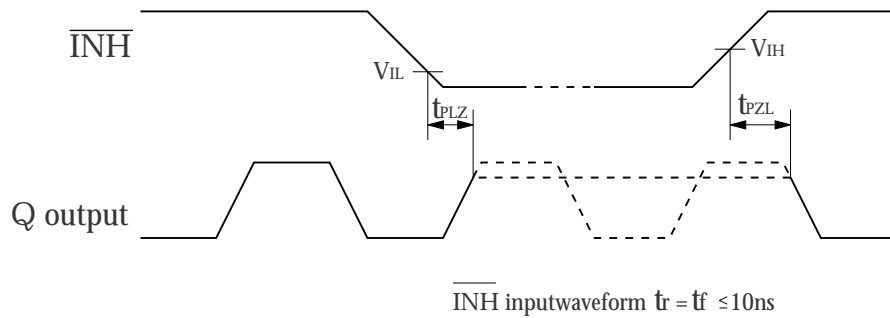
**Output duty cycle (CMOS)**



**Output duty cycle (TTL)**



## Output Enable/Disable Delay



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